



JMD280KD18T2W

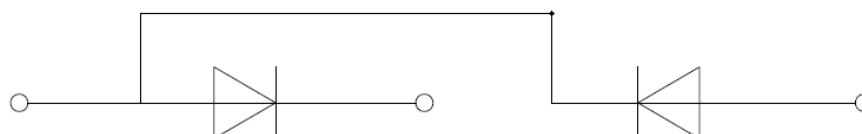
Diode Module

Features

- A package of series of two diodes
- Heat transfer through alumina ceramic and metal substrate
- Welding by vacuum welding technology,

Product Summary

Parameter	Value	Unit
V_{RRM}	1800	V
$I_{F(AV)}$ (@ $T_C = 100^\circ\text{C}$)	280	A
I_{FSM} (@ $t_p = 10\text{ms}$)	8800	A
$V_F(\text{Max})$	1.60	V



Absolute Maximum Ratings (@ $T_C = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Conditions	Symbol	Values	Unit
Repetitive peak reverse voltage	$T_{vj} = 25^\circ\text{C}$	V_{RRM}	1800	V
Non-repetitive peak reverse voltage	$T_{vj} = 25^\circ\text{C}$	V_{RSM}	1900	V
Average forward current	$T_C = 100^\circ\text{C}$	$I_{F(AV)}$	280	A
Forward surge current	1/2 cycle, Sine wave, 50Hz	I_{FSM}	8800	A
I^2t value for fusing	$T_{vj} = 25$	I^2t	387200	A^2s
RMS isolation voltage	A.C 50Hz(1s/1min)	V_{ISO}	3600/3000	V
Junction temperature range		T_J	-40 ~ +150	
Storage temperature range		T_{stg}	-40 ~ +125	

**Electrical Characteristics (@ $T_C = 25^\circ\text{C}$ unless otherwise specified)**

Parameter	Conditions	Symbol	Values			Unit
			Min.	Typ.	Max.	
Peak forward voltage	$I_F=840\text{A}$, $t_p=380\mu\text{s}$	V_F			1.60	V
Reverse leakage current	$V_R = V_{RRM}$, $T_{vj} = 25$	I_{RRM}			100	μA
	$V_R = V_{RRM}$, $T_{vj} = 150$				90	mA
Threshold voltage	$T_{vj} = 150$, for power loss calculation only	V_{TO}			0.8	V
Dynamic resistance		r_T			0.78	m

Thermal Characteristics (@ $T_C = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Conditions	Symbol	Values			Unit
			Min.	Typ.	Max.	
Thermal resistance, junction to case	per diode	$R_{th(j-c)}$		0.12		/W
Thermal resistance, case to heatsink	per diode	$R_{th(c-s)}$		0.06		/W
Mounting torque	Module and heatsink fixed torque M5	M	4.25		5.75	N·m
	Electrode connection torque, screw M6		4.25		5.75	N·m

Ordering Information

Device	Marking	Package	Weight	Inner Box	Pre Carton
JMD280KD18T2W	JMD280KD18T2W	T2	170 10g/PCS	6 PCS	72 PCS

